

VIOLET DIODE LASER AT 415nm

RN-III-415/1~100mW

产品描述

It features ultra compact design, long lifetime, cost-effectiveness and easy operation.

They are used in measurement, communication, spectrum analysis, etc.

产品参数

RN-III-415/1~100mW		
Central wavelength (nm)	415±5	
Operating mode	CW	
Output power (mW)	>1.10.20....100	
Power stability (rms, over 4 hours)	<1%, <2%, <3% (<0.5%, optional)	
Transverse mode	Near TEM ₀₀	
M ² factor	<1.5 (<1.2, optional)	
Beam diameter at the aperture (1/e ² , mm)	~3.5 (~1.2, optional)	
Beam divergence , fullangle(mrad)	<1.0	
Polarization ratio	>50:1(>100:1optional) Horizontal±5degree (Vertical Optional)	
Warm-up time (minutes)	<5	
Pointing stability after warm-up (mrad)	<0.05	
Beam height from baseplate (mm)	24.8	
Operating temperature (°C)	10~35	
Power supply	85-264VAC 100-240VAC	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz) PSU-A-D (Frequency for 30kHz -100kHz)
TTL / Analog modulation		TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional
Expected lifetime (hours)	10000	
Warranty	1 year	